

CMPT491E

**ENHANCED SPECIFICATION
SURFACE MOUNT
NPN SILICON TRANSISTOR**



www.centrasemi.com



SOT-23 CASE

DESCRIPTION:

The CENTRAL SEMICONDUCTOR CMPT491E type is an Enhanced version of the industry standard 491 NPN silicon transistor. This device is manufactured by the epitaxial planar process and epoxy molded in an SOT-23 surface mount package. The CMPT491E features Low $V_{CE(SAT)}$, high h_{FE} , and has been designed for high current general purpose amplifier applications.

MARKING CODE: C49

COMPLEMENTARY TYPE: CMPT591E

FEATURED ENHANCED SPECIFICATIONS:

- ◆ $V_{CE(SAT)}$ @ 1.0A = 0.4V MAX (from 0.5V MAX)
- ◆ h_{FE} @ 500mA = 200 MIN (from 100 MIN)

MAXIMUM RATINGS: ($T_A=25^\circ\text{C}$)

	SYMBOL		UNITS
Collector-Base Voltage	V_{CBO}	80	V
Collector-Emitter Voltage	V_{CEO}	60	V
Emitter-Base Voltage	V_{EBO}	5.0	V
Continuous Collector Current	I_C	1.0	A
Continuous Base Current	I_B	200	mA
Peak Collector Current	I_{CM}	2.0	A
Power Dissipation	P_D	350	mW
Operating and Storage Junction Temperature	T_J, T_{stg}	-65 to +150	$^\circ\text{C}$
Thermal Resistance	θ_{JA}	357	$^\circ\text{C/W}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^\circ\text{C}$ unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I_{CBO}	$V_{CB}=60\text{V}$		100	nA
I_{EBO}	$V_{EB}=4.0\text{V}$		100	nA
BV_{CBO}	$I_C=100\mu\text{A}$	80		V
BV_{CEO}	$I_C=10\text{mA}$	60		V
BV_{EBO}	$I_E=100\mu\text{A}$	5.0		V
◆ $V_{CE(SAT)}$	$I_C=500\text{mA}, I_B=50\text{mA}$		0.20	V
◆ $V_{CE(SAT)}$	$I_C=1.0\text{A}, I_B=100\text{mA}$		0.40	V
$V_{BE(SAT)}$	$I_C=1.0\text{A}, I_B=100\text{mA}$		1.1	V
$V_{BE(ON)}$	$V_{CE}=5.0\text{V}, I_C=1.0\text{A}$		1.0	V
◆ h_{FE}	$V_{CE}=5.0\text{V}, I_C=1.0\text{mA}$	200		
◆ h_{FE}	$V_{CE}=5.0\text{V}, I_C=500\text{mA}$	200	600	
h_{FE}	$V_{CE}=5.0\text{V}, I_C=1.0\text{A}$	50		
h_{FE}	$V_{CE}=5.0\text{V}, I_C=2.0\text{A}$	15		
f_T	$V_{CE}=10\text{V}, I_C=50\text{mA}, f=100\text{MHz}$	150		MHz
C_{ob}	$V_{CB}=10\text{V}, I_E=0, f=1.0\text{MHz}$		10	pF

◆ Enhanced specification

R4 (27-January 2010)

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SOT-23 CASE - MECHANICAL OUTLINE



LEAD CODE:

- 1) Base
- 2) Emitter
- 3) Collector

MARKING CODE: C49

DIMENSIONS				
SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.003	0.007	0.08	0.18
B	0.006	-	0.15	-
C	-	0.005	-	0.13
D	0.035	0.043	0.89	1.09
E	0.110	0.120	2.80	3.05
F	0.075		1.90	
G	0.037		0.95	
H	0.047	0.055	1.19	1.40
I	0.083	0.098	2.10	2.49
J	0.014	0.020	0.35	0.50

SOT-23 (REV: R3)

R4 (27-January 2010)